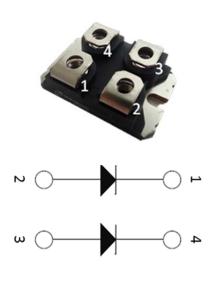


SiC SBD Parallel

Power Module



Parallel



$V_{RRM} = 600V$ $I_{DAV} = 20A @T_C = 125^{0}C$

Features

· SiC Schottky Diode

- Zero reverse recovery
- Zero forward recovery
- Temperature Independent switching behavior
- Positive temperature coefficient on V_F
- Low stray inductance
- High junction temperature operation

Applications

- Supplies for DC power equipment
- Rectifier for induction heating
- Welding equipment
- High temperature and rectifiers

Benefits

- Outstanding performance at high frequency operation
- Low losses and Low EMI noises
- Very rugged and easy mount
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- \bullet Easy paralleling due to positive $T_C\, of\, V_F$
- RoHS Compliant

Absolute Maximum Ratings (T_i=25°C unless otherwise specified)

Parameters	Symbol	Conditions	Specifications	Units
Maximum Reverse Voltage	V_{RRM}		600	V
Average Forward Current (per SBD)	I _{DAV}	$T_{\rm C} = 25{}^{\rm 0}{\rm C}$	46	Α
		$T_{\rm C} = 125{}^{\rm 0}{\rm C}$	25	Α
Non-repetitive Forward Surge Current	I _{FSM}	$tp=8.3 \text{ ms}, T_C = 25 ^{\circ}\text{C}$	192	Α
		tp=10 μ s, T _C = 25 0 C	480	Α
Operating Junction Temperature	T _j		-55 ~ 175	°C
Storage Temperature	T _{STG}		-55 ~ 1 50	°C

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Electrical Characteristics (T_j=25°C unless otherwise specified)

Parameters	Symbol	Conditions	Min	Тур	Max	Units
Maximum peak repetitive reverse voltage	V _{RRM}		600			V
Maximum Reverse Leakage Current	I _{RM}	$V_R = 600V, T_j = 25$ °C		2.6	200	μΑ
per diode		$V_R = 600V, T_j = 150$ °C		970		μΑ
Diode Forward Voltage	V _F	$I_F = 20A, T_j = 25$ °C		1.5	1.7	V
		$I_F = 20A, T_j = 175$ °C		2.5	2.8	V
Total Capacitive Charge	Q _C	VR=600 V, IF <if,max< td=""><td></td><td>50</td><td></td><td>nC</td></if,max<>		50		nC
Switching Time	t _C	$dI_F/dt = 200 A/\mu s$, $T_j = 175 ^{0}C$			10	ns
Total Capacitance	С	V _R = 1V, f = 1 MHz		974		pF
		V _R = 300V, f = 1 MHz		86		pF
		V _R = 600V, f = 1 MHz		82		pF

Thermal and Package Characteristics (T_j=25°C unless otherwise specified)

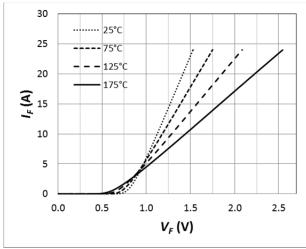
Parameters	Symbol	Conditions	Min	Тур	Max	Units
Junction to Case Thermal Resistance	R _{THJC}	Per Diode			0.77	°C /W
Junction to Ambient Thermal Resistance	R _{THJA}	Per Diode			20	°C /W
Mounting Torque	M _d				1.5	N-m
Terminal Connection Torque	M _{dt}		1.3		1.5	N-m
Package Weight	W _t			32		g
Isolation Voltage	V _{ISOL}	I _{ISOL} < 1mA, 50/60Hz, t=1 min	2500	V		

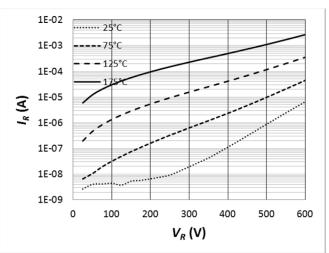
Product Number and Pin Descriptions

Part Number	Rating	Pin 1	Pin 2	Pin 3	Pin 4
GHXS020A060S-D3	600V, 20A	Cathode 1	Anode 1	Anode 2	Cathode 2

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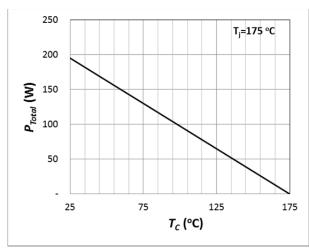


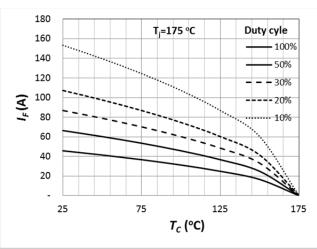




Forward Characteristics (parameterized on Tj)

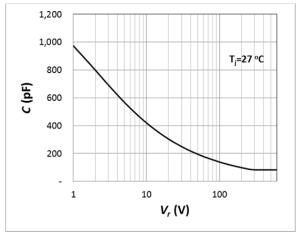
Reverse Characteristics (parameterized on Tj)

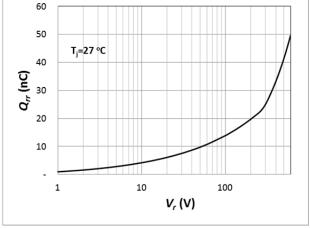




Power Derating

Current Derating



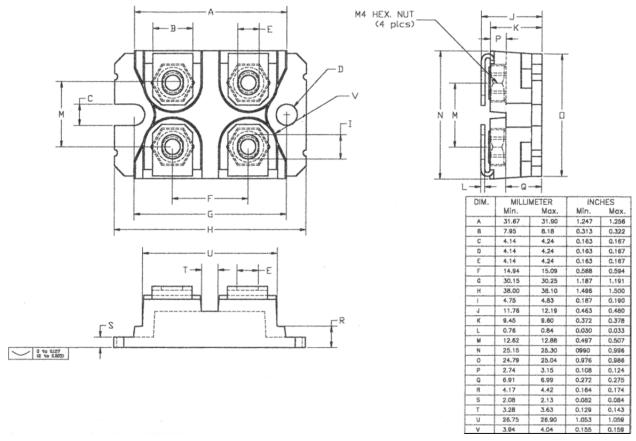


Capacitance Curve

Recovery Charge



SOT-227 Package Outline



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Revision History

Date	Revision	Notes
9/6/2013	1.0	Initial release
6/4/2014	1.1	Add the part number, pin assignment table.
01/03/2020	1.2	Applied company name change

Notes

RoHS Compliance

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented March, 2013. RoHS Declarations for this product can be obtained from the Product Documentation sections of www.SemiQ.com.

REACh Compliance

REACh substances of high concern (SVHC) information is available for this product. Since the European Chemicals Agency (ECHA) has published notice of their intent to frequently revise the SVHC listing for the foreseeable future, please contact our office at SemiQ Headquarters in Lake Forest, California to insure you get the most up-to-date REACh SVHC Declaration. REACh banned substance information (REACh Article 67) is also available upon request.

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<u>25.163.2453.0</u> <u>25.16</u>	63.4253.0 25.	190.2053.0	25.194.3453.0	25.320.4853.1	25.320.5253.1	25.326.3253.1	25.326.3553.1	25.330.1653.1
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T512F-YEB T513F	T514F T554	<u>T612FSE</u>	25.161.3453.0	25.179.2253.0	25.194.3253.0	25.325.1253.1	25.326.4253.1	25.330.0953.1
<u>25.332.4353.1</u> <u>25.35</u>	50.1653.0 25.	350.2453.0	25.352.1453.0	25.352.1653.0	25.352.2453.0	25.352.5453.1	25.522.3353.0	25.602.4053.0
25.640.5053.0								